

# Silicon SPDT Switch, Nonreflective, 100 MHz to 44 GHz

**Enhanced Product** 

ADRF5026-EP

#### **FEATURES**

Ultrawideband frequency range: 100 MHz to 44 GHz Nonreflective design

Low insertion loss: 1.2 dB to 18 GHz, 1.7 dB to 26 GHz, 2.4 dB to 40 GHz, 3.8 dB to 44 GHz

High isolation: 55 dB to 18 GHz, 53 dB to 26 GHz, 50 dB to 40 GHz, 45 dB to 44 GHz

High input linearity: 27 dBm typical P1dB, 53 dBm typical IP3

High power handling: 24 dBm insertion loss path,

24 dBm isolation path

All off state control

No low frequency spurious signals

0.1 dB RF settling time: 40 ns typical

20-terminal, 3 mm × 3 mm LGA package

Pin compatible with ADRF5027, low frequency cutoff version

## **ENHANCED PRODUCT FEATURES**

Supports defense and aerospace applications (AQEC standard)
Military temperature range (-55°C to +105°C)
Controlled manufacturing baseline
1 assembly/test site
1 fabrication site
Product change notification
Qualification data available on request

## **APPLICATIONS**

Industrial scanners
Test and instrumentation
Cellular infrastructure: 5G mmWave
Military radios, radars, electronic counter measures (ECMs)
Microwave radios and very small aperture terminals (VSATs)

### **GENERAL DESCRIPTION**

The ADRF5026-EP is a nonreflective, single-pole, double-throw (SPDT) RF switch manufactured in a silicon process.

The ADRF5026-EP operates from 100 MHz to 44 GHz with better than 3.8 dB of insertion loss and 45 dB of isolation. The ADRF5026-EP features an all off control, where both RF ports are in an isolation state. The ADRF5026-EP has a nonreflective design and both of the RF ports are internally terminated to 50  $\Omega$ .

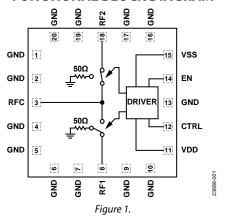
The ADRF5026-EP requires a dual-supply voltage of +3.3 V and -3.3 V. The device employs CMOS and low voltage transistor transistor logic (LVTTL)-compatible controls.

The ADRF5026-EP is pin compatible with the ADRF5027 low frequency cutoff version, which operates from 9 kHz to 44 GHz.

Rev. 0

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#### **FUNCTIONAL BLOCK DIAGRAM**



The ADRF5026-EP RF ports are designed to match a characteristic impedance of 50  $\Omega$ . For ultrawideband products, impedance matching on the RF transmission lines can further optimize high frequency insertion loss and return loss characteristics. Refer to the ADRF5026 data sheet for an example of a matched circuit that achieves a flat insertion loss response of 2.4 dB from 28 GHz to 43 GHz.

The ADRF5026-EP comes in a 20-terminal, 3 mm  $\times$  3 mm, RoHS compliant, land grid array (LGA) package and can operate from  $-55^{\circ}$ C to  $+105^{\circ}$ C.

Additional application and technical information can be found in the ADRF5026 data sheet.

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# ADRF5026-EP Enhanced Product

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# **REVISION HISTORY**

10/2020—Revision 0: Initial Version

Enhanced Product ADRF5026-EP

# **SPECIFICATIONS**

# **ELECTRICAL SPECIFICATIONS**

 $VDD = 3.3 \text{ V}, VSS = -3.3 \text{ V}, CTRL \text{ pin voltage } (V_{CTRL}) = EN \text{ pin voltage } (V_{EN}) = 0 \text{ V or VDD}, \text{ and } T_{CASE} = 25^{\circ}\text{C in a 50 } \Omega \text{ system, unless otherwise noted.}$ 

Table 1.

Parameter	Symbol	Test Conditions/Comments	Min Typ	Max	Unit
FREQUENCY RANGE			100	44,000	MHz
INSERTION LOSS	IL				
Between RFC and RF1/RF2		100 MHz to 18 GHz	1.2		dB
		18 GHz to 26 GHz	1.7		dB
		26 GHz to 35 GHz	2.2		dB
		35 GHz to 40 GHz	2.4		dB
		40 GHz to 44 GHz <sup>1</sup>	3.8		dB
RETURN LOSS	RL				
RFC and RF1/RF2 (On)		100 MHz to 18 GHz	22		dB
		18 GHz to 26 GHz	12		dB
		26 GHz to 35 GHz	9		dB
		35 GHz to 40 GHz	10		dB
		40 GHz to 44 GHz <sup>1</sup>	7		dB
RF1/RF2 (Off)		100 MHz to 18 GHz	23		dB
, = (=,		18 GHz to 26 GHz	23		dB
		26 GHz to 35 GHz	21		dB
		35 GHz to 40 GHz	13		dB
		40 GHz to 44 GHz <sup>1</sup>	12		dB
ISOLATION		TO GITE TO THE TELESTIC TO GITE TO GIT GITE TO			- 45
Between RFC and RF1/RF2		100 MHz to 18 GHz	55		dB
between in Cana in 17 in 2		18 GHz to 26 GHz	53		dB
		26 GHz to 35 GHz	53		dB
		35 GHz to 40 GHz	50		dB
		40 GHz to 44 GHz	45		dB
Between RF1 and RF2		100 MHz to 18 GHz	63		dB
between in 1 and in 2		18 GHz to 26 GHz	60		dB
		26 GHz to 35 GHz	60		dB
		35 GHz to 40 GHz	63		dB
		40 GHz to 44 GHz	55		dB
SWITCHING CHARACTERISTICS		40 GHZ 10 44 GHZ	33		ав
Rise and Fall Time	t <sub>RISE</sub> , t <sub>FALL</sub>	10% to 90% of RF output	3		ns
On and Off Time	ton, toff	50% of triggered V <sub>CTRL</sub> to 90% of RF output	14		ns
RF Settling Time	CON, COFF	30% of triggered verke to 90% of Ki output	14		113
0.1 dB		50% of triggered V <sub>CTRL</sub> to 0.1 dB of final RF output	40		ns
0.05 dB		50% of triggered VCTRL to 0.05 dB of final RF output	45		
		100 MHz to 40 GHz	43		ns
INPUT LINEARITY	D1 -ID	100 MHz to 40 GHz	27		-10
1 dB Compression	P1dB	T	27		dBm
Third-Order Intercept	IP3	Two-tone input power = 12 dBm each tone, $\Delta f = 1$ MHz	53		dBm
SUPPLY CURRENT	1.	VDD and VSS pins	_		
Positive	I <sub>DD</sub>		2		μA
Negative	Iss		100		μΑ

**Enhanced Product** ADRF5026-EP

Parameter	Symbol	Test Conditions/Comments	Min	Тур	Max	Unit
DIGITAL CONTROL INPUTS		CTRL and EN pins				
Voltage						
Low	V <sub>INL</sub>		0		8.0	V
High	$V_{INH}$		1.2		3.3	V
Current						
Low and High Current	I <sub>INL</sub> , I <sub>INH</sub>			<1		μΑ
RECOMMENDED OPERATING CONDITONS						
Supply Voltage						
Positive	VDD		3.15		3.45	V
Negative	VSS		-3.45		-3.15	V
Digital Control Voltage	$V_{\text{CTRL}}$ , $V_{\text{EN}}$		0		VDD	V
RF Input Power <sup>2</sup>	P <sub>IN</sub>	$f = 100 \text{ MHz to } 40 \text{ GHz}, T_{CASE} = 85^{\circ}\text{C}^{3}$				
Insertion Loss Path		RF signal is applied to RFC or through connected RF1/RF2			24	dBm
Isolation Path		RF signal is applied to terminated RF1/RF2			24	dBm
Hot Switching		RF signal is present at RFC while switching between RF1 and RF2			24	dBm
Case Temperature	T <sub>CASE</sub>		-55		+105	°C

<sup>&</sup>lt;sup>1</sup> Impedance matching on RF transmission lines improves high frequency performance. Refer to the ADRF5026 data sheet for more information.

<sup>2</sup> For power derating vs. frequency, see Figure 2 and Figure 3. This power derating is applicable for insertion loss path, isolation path, and hot switching power

 $<sup>^{3}</sup>$  For 105°C operation, the power handling degrades from the  $T_{CASE} = 85$ °C specification by 3 dB.

Enhanced Product ADRF5026-EP

# ABSOLUTE MAXIMUM RATINGS

For recommended operating conditions, see Table 1.

Table 2.

Parameter	Rating
Positive Supply Voltage	−0.3 V to +3.6 V
Negative Supply Voltage	−3.6 V to +0.3 V
Digital Control Inputs	
Voltage	-0.3 V to VDD + 0.3 V
Current	3 mA
RF Input Power <sup>1</sup> (100 MHz to 40 GHz at	
$T_{CASE} = 85^{\circ}C^{2}$	
Insertion Loss Path	26 dBm
Isolation Path	25 dBm
Hot Switching	25 dBm
Temperature	
Junction, T <sub>J</sub>	135°C
Storage Range	−65°C to +150°C
Reflow	260°C
Electrostatic Discharge (ESD) Sensitivity	
Human Body Model (HBM)	
RFC, RF1, RF2 Pins	500 V
Digital Pins	2000 V
Charged Device Model (CDM)	1250 V

<sup>&</sup>lt;sup>1</sup> For power derating vs. frequency, see Figure 2 and Figure 3. This power derating is applicable for insertion loss path, isolation path, and hot switching power specifications.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

Only one absolute maximum rating can be applied at any one time

# THERMAL RESISTANCE

Thermal performance is directly linked to printed circuit board (PCB) design and operating environment. Careful attention to PCB thermal design is required.

 $\theta_{\rm IC}$  is the junction to case bottom (channel to package bottom) thermal resistance.

**Table 3. Thermal Resistance** 

Package Type	θ <sub>JC</sub>	Unit	
CC-20-4			
Through Path	423	°C/W	
Terminated Path	241	°C/W	

### **POWER DERATING CURVES**

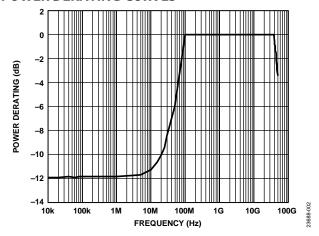


Figure 2. Power Derating vs. Frequency, Low Frequency Detail,  $T_{CASE} = 85^{\circ}C$ 

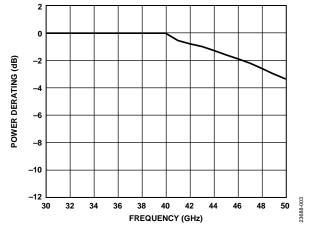


Figure 3. Power Derating vs. Frequency, High Frequency Detail,  $T_{CASE} = 85$ °C

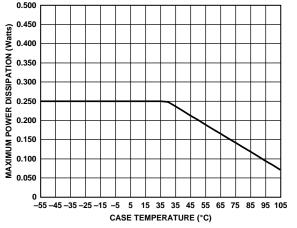


Figure 4. Maximum Power Dissipation vs. Case Temperature

### **ESD CAUTION**



**ESD** (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

 $<sup>^2</sup>$  For 105°C operation, the power handling degrades from the  $T_{\text{CASE}} = 85^{\circ}\text{C}$  specification by 3 dB.

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# PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

# ADRF5026-EP

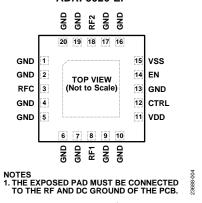


Figure 5. Pin Configuration

**Table 4. Pin Function Descriptions** 

Pin No.	Mnemonic	Description
1, 2, 4, 5, 6, 7, 9, 10, 13, 16, 17, 19, 20	GND	Ground. These pins must be connected to the RF and dc ground of the PCB.
3	RFC	RF Common Port. This pin is dc-coupled to 0 V and ac matched to 50 $\Omega$ . No dc blocking capacitor is necessary when the RF line potential is equal to 0 V dc. See Figure 6 for the interface schematic.
8	RF1	RF1 Port. This pin is dc-coupled to 0 V and ac matched to 50 $\Omega$ . No dc blocking capacitor is necessary when the RF line potential is equal to 0 V dc. See Figure 6 for the interface schematic.
11	VDD	Positive Supply Voltage.
12	CTRL	Control Input Voltage. See Figure 7 for the interface schematic.
14	EN	Enable Input Voltage. See Figure 7 for the interface schematic.
15	VSS	Negative Supply Voltage.
18	RF2	RF2 Port. This pin is dc-coupled to 0 V and ac matched to 50 $\Omega$ . No dc blocking capacitor is necessary when the RF line potential is equal to 0 V dc. See Figure 6 for the interface schematic.
	EPAD	Exposed Pad. The exposed pad must be connected to the RF and dc ground of the PCB.

## **INTERFACE SCHEMATICS**

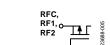


Figure 6. RFC, RF1, RF2 Interface Schematic

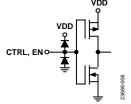


Figure 7. CTRL, EN Interface Schematic

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# TYPICAL PERFORMANCE CHARACTERISTICS

VDD = 3.3 V, VSS = -3.3 V,  $V_{CTRL}/V_{EN}$  = 0 V or VDD, and  $T_{CASE}$  = 25°C in a 50  $\Omega$  system, unless otherwise noted.

Insertion loss is measured on the probe matrix board using ground-signal-ground (GSG) probes close to the RFx pins. Signal coupling between the probes limits the isolation performance of the ADRF5026-EP. Isolation is measured on the ADRF5026-EVALZ evaluation board. See the ADRF5026 data sheet for details on the ADRF5026-EVALZ evaluation board and probe matrix board.

See the ADRF5026 data sheet for a full set of Typical Performance Characteristics plots.

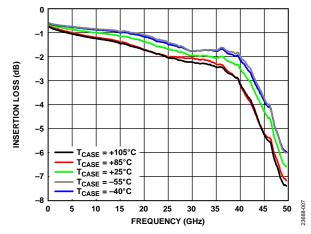


Figure 8. Insertion Loss vs. Frequency over Temperature

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# **OUTLINE DIMENSIONS**

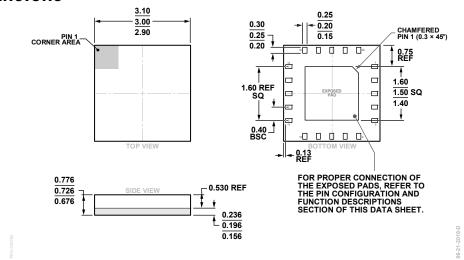


Figure 9. 20-Terminal Land Grid Array [LGA]  $3 \text{ mm} \times 3 \text{ mm}$  Body and 0.726 mm Package Height (CC-20-4) Dimensions shown in millimeters

## **ORDERING GUIDE**

Model <sup>1</sup>	Temperature Range	Package Description	Package Option	Marking Code
ADRF5026SCCZ-EP	−55°C to +105°C	20-Terminal Land Grid Array [LGA]	CC-20-4	6EP
ADRF5026SCCZ-EPR7	−55°C to +105°C	20-Terminal Land Grid Array [LGA]	CC-20-4	6EP

<sup>&</sup>lt;sup>1</sup> Z = RoHS Compliant Part.



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